# NSN 5962-01-214-4461

Memory Microcircuit - Page 1 of 1



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# **Body Length:**

Between 0.942 inches and 0.990 inches

#### **Body Width:**

0.302 inches

# **Body Height:**

Between 0.145 inches and 0.175 inches

#### Storage Tempurature Range:

-65.0 to 150.0 degrees celsius

#### **End Application:**

Radar set an/fps-115

#### **Features Provided:**

3-state output and programmable and bidirectional and hermetically sealed and schottky

#### **Inclosure Material:**

Ceramic and glass

#### Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

Transistor-transistor logic

#### Input Circuit Pattern:

8 input

# **Terminal Surface Treatment:**

Solder

# Voltage Rating And Type Per Characteristic:

7.0 volts power source

#### Time Rating Per Chacteristic:

30.00 nanoseconds propagation delay time, low to high level output and 30.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Pal

#### **Terminal Type And Quantity:**

20 printed circuit

# Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

Fiig:

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